TOSHIBA Photocoupler GaAs IRED + Photo-Triac

## **TLP260J**

Triac Drivers
Programmable Controllers
AC-Output Modules
Solid-State Relays

The TOSHIBA mini-flat coupler TLP260J is a small-outline coupler suitable for surface mount assembly.

The TLP260J consists of a photo-triac optically coupled to a gallium arsenide infrared-emitting diode.

Peak off-state voltage : 600 V (min)
 Trigger LED current : 10 mA (max)
 On-state current : 70 mA (max)
 Isolation voltage : 3000 Vrms (min)

UL approved: UL1577, File No.E67349

• Option (V4) VDE approved : EN60747-5-5 (Note1)

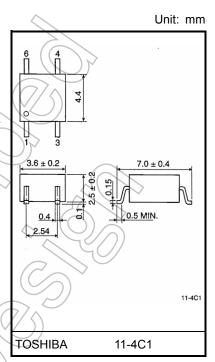
Note 1: When a EN60747-5-5 approved type is needed,

please designate "Option(V4)"

Maximum operating insulation voltage : 565 Vpk Highest permissible overvoltage : 6000 Vpk

Construction Mechanical Rating

Creepage distance : 4.0 mm (min)
Clearance : 4.0 mm (min)
Insulation thickness : 0.4 mm (min)



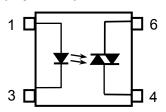
Weight: 0.09 g (typ.)

#### **Trigger LED Current**

	Trigger LED C	Product	
Classification	$V_{T} = 6 V, T$	Classification	
<	Min	Max	Marking
Standard	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	10 />	Blank

Note: Be sure to use standard product type names when submitting type names for safety certification testing, i.e., TLP260J.

# Pin Configuration (top View)



- 1. Anode
- 3. Cathode
- 4. Triac Terminal
- 6. Triac Terminal

Start of commercial production 1996-07

#### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	;	Symbol	Rating	Unit
	Forward current	lF	50	mA	
	Forward current derating (T	ΔI <sub>F</sub> / °C	-0.7	mA / °C	
	Peak forward current (100 μ	us pulse, 100 pps)	IFP	1	A
LED	Reverse voltage		VR	5	V (
	Diode power dissipation		P <sub>D</sub>	100	mW
	Diode power dissipation der	rating (Ta ≥ 53°C)	ΔP <sub>D</sub> /°C	-1.4	mW/°C
	Junction temperature		Tj	125	(°C)
	Off-state output terminal vo	VDRM	600	K	
	On-state RMS current	Ta = 25°C	IT (DAG)	70	
		Ta = 70°C	T(RMS)	40	mA
	On-state current derating (T	ΔI <sub>T</sub> / °C	-0.67	mA / °C	
Detector	Peak on-state current (100	μs pulse, 120 pps)	ITP	$()^2 \wedge$	A
Dete	Peak nonrepetitive surge cu (P <sub>W</sub> = 10 ms)	urrent	ITSM	1.2	A (
	Output power dissipation		Po	200	mW
	Output power dissipation de	erating (Ta ≥ 25°C)	ΔP <sub>0</sub> /°C	-2.0	mW / °C
	Junction temperature		Ti	100	(/°C)
Storage temperature range			Tstg	-55 to 125	°C
Operating temperature range			T <sub>opr</sub>	-40 to 100	\ °C
Lead s	oldering temperature (10 s)		T <sub>sol</sub>	260	∕ °C
Isolatio	on voltage (AC, 60 s, R.H. ≤ 6	BVS	3000	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered as a two-terminal device: Pins 1 and 3 shorted together and pins 4 and 6 shorted together.

#### **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vac	_	_	240	Vac
Forward current	lF	15	20	25	mA
Peak on-state current	ITP	_	_	1	Α
Operating temperature	T <sub>opr</sub>	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

### **Electrical Characteristics (Ta = 25°C)**

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	IF = 10 mA	1.0	1.15	1.3	V
ED	Reverse current	IR	V <sub>R</sub> = 5 V	_	_	10	μΑ
	Capacitance	Ст	VF = 0 V, f = 1 MHz	/_	30	_	pF
	Peak off-state current	IDRM	V <sub>DRM</sub> = 600 V	(-)	10	1000	nA
	Peak on-state voltage	VTM	I <sub>TM</sub> = 70 mA	1	))1.7	2.8	V
for	Holding current	lн	(7	) \ )	1.0	_	mA
Detector	Critical rate of rise of off-state voltage	dv / dt	V <sub>in</sub> = 240 Vrms, Ta = 85°C (Fig. 1)		500	_	V / µs
	Critical rate of rise of commutating voltage	dv / dt(c)	I <sub>T</sub> = 15 mA, V <sub>in</sub> = 60 Vrms (Fig. 1)	_	0.2	-	V / µs

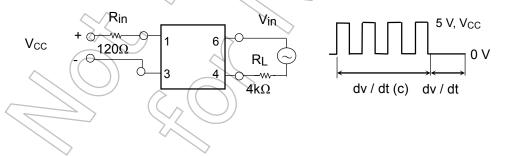
## Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I <sub>FT</sub>	V <sub>T</sub> = 6 V		5	10	mA
Turn-on time	ton	$V_D = 6 \rightarrow 4 \text{ V}, R_L = 100\Omega$ $I_F = \text{rated } I_{FT} \times 1.5$		30	100	μs

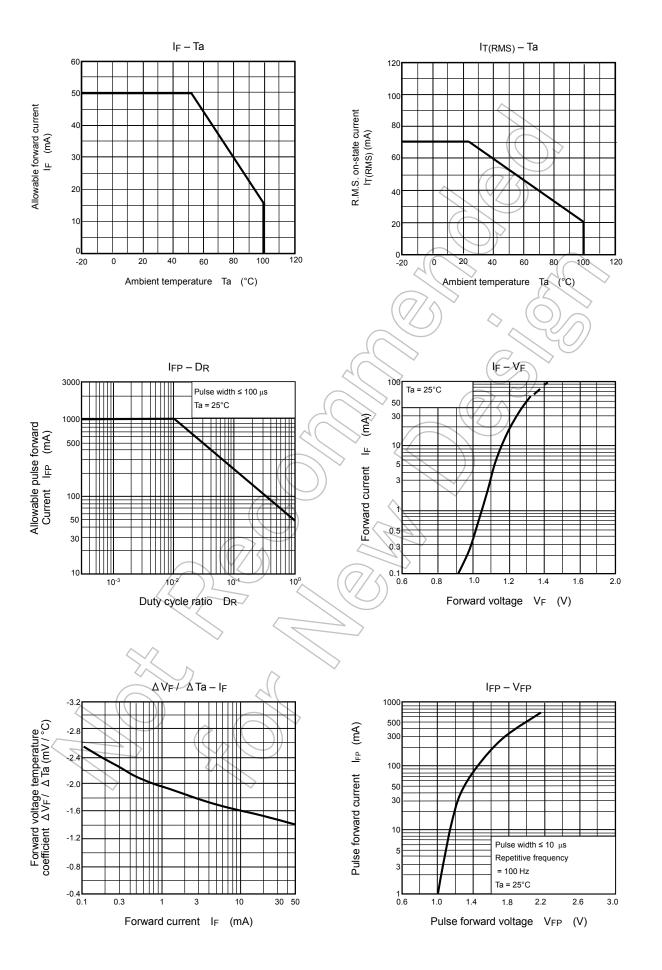
## Isolation Characteristics (Ta = 25°C)

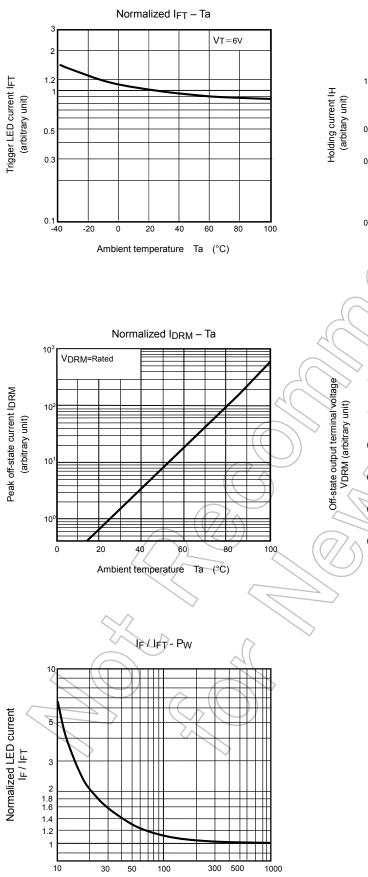
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	(CS)	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	V <sub>S</sub> = 500 V, R.H. ≤ 60%	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
_ ((7)		AC, 60 s	3000	_	_	Vrms
Isolation voltage	BVS	AC, 1 s, in oil	_	5000	_	VIIIIS
		DC, 60 s, in oil	_	5000	_	Vdc

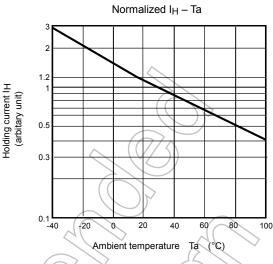
Fig. 1: dv / dt test circuit

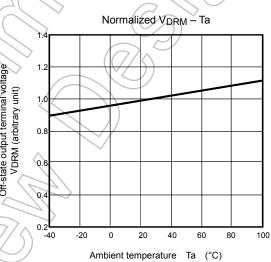


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LED current pulse width  $P_W$  ( $\mu s$ )

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